P-Channel Enhancement Mode Power MOSFET

Description

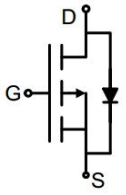
The G45P02D3 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge. It can be used in a wide variety of applications.

General Features

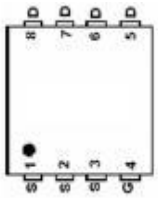
- V_{DS} -20V
- I_D (at V_{GS} = -10V) -45A
- $R_{DS(ON)}$ (at V_{GS} = -4.5V) < 7.5mΩ
- $R_{DS(ON)}$ (at V_{GS} = -2.5V) < 10mΩ
- 100% Avalanche Tested
- RoHS Compliant

Application

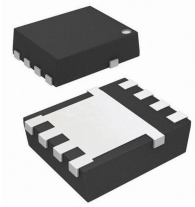
- Power switch
- DC/DC converters



Schematic diagram



pin assignment



DFN3x3-8L

Ordering Information

Device	Package	Marking	Packaging
G45P02D3	DFN3x3-8L	G45P02	5000pcs/Reel

Absolute Maximum Ratings T_C = 25ºC, unless otherwise noted

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-20	V
Continuous Drain Current	I_D	-45	A
Pulsed Drain Current (note1)	I_{DM}	-180	A
Gate-Source Voltage	V_{GS}	±12	V
Power Dissipation	P_D	29	W
Single pulse avalanche energy （note2）	E_{AS}	81	mJ
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 To 150	ºC

Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient	R_{thJA}	75	ºC/W
Maximum Junction-to-Case	R_{thJC}	4.2	ºC/W

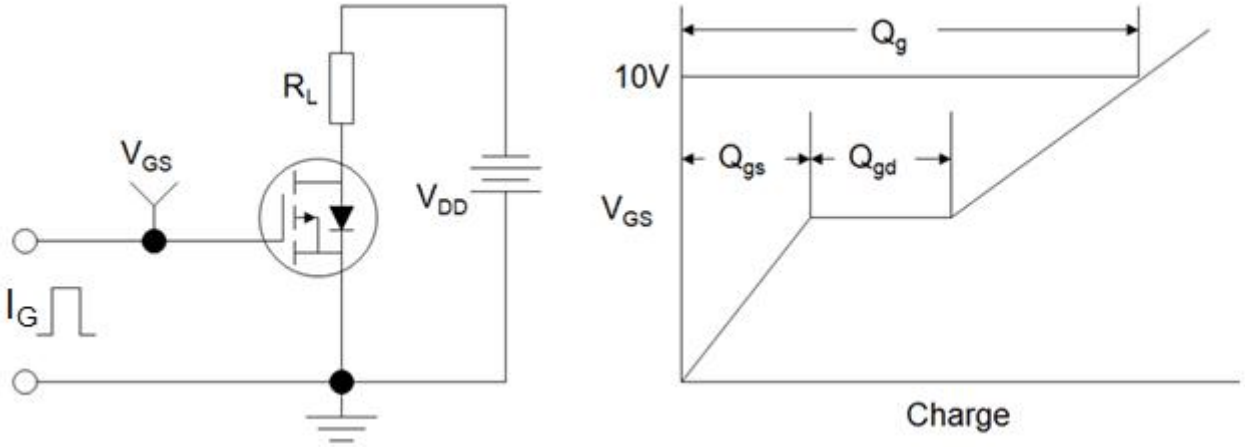
Specifications T_J = 25ºC, unless otherwise noted

Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Static Parameters						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D = -250μA	-20	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = -20V, V_{GS} = 0V	--	--	-1	μA
Gate-Source Leakage	I_{GSS}	V_{GS} = ±12V	--	--	±100	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = -250μA	-0.4	-0.65	-1	V
Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS} = -4.5V, I_D = -10A	--	6	7.5	mΩ
		V_{GS} = -2.5V, I_D = -10A	--	8	10	
Forward Transconductance	g_{FS}	V_{DS} = -5V,I_D = -10A	--	72	--	S
Dynamic Parameters						
Input Capacitance	C_{iss}	V_{GS} = 0V, V_{DS} = -10V, f = 1.0MHz	--	4867	--	pF
Output Capacitance	C_{oss}		--	642	--	
Reverse Transfer Capacitance	C_{rss}		--	593	--	
Total Gate Charge	Q_g	V_{DD} = -10V, I_D = -10A, V_{GS} = -10V	--	44	--	nC
Gate-Source Charge	Q_{gs}		--	9	--	
Gate-Drain Charge	Q_{gd}		--	11	--	
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = -10V, I_D = -10A, R_G = 3Ω	--	18	--	ns
Turn-on Rise Time	t_r		--	32	--	
Turn-off Delay Time	$t_{d(off)}$		--	136	--	
Turn-off Fall Time	t_f		--	59	--	
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	I_S	T_C = 25ºC	--	--	-45	A
Body Diode Voltage	V_{SD}	T_J = 25ºC, I_{SD} = -10A, V_{GS} = 0V	--	--	-1.2	V
Reverse Recovery Charge	Q_{rr}	I_F = -10A, V_{GS} = 0V di/dt=-500A/us	--	100	--	nC
Reverse Recovery Time	T_{rr}		--	33	--	ns

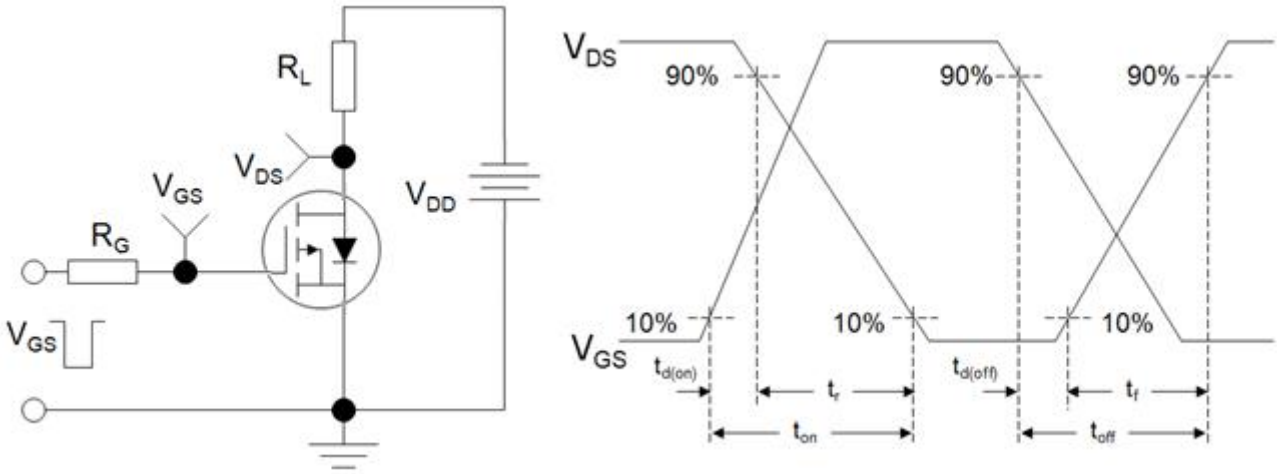
Notes

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. EAS condition : Tj=25℃ ,VDD=-20V,VGS=-10V,L=0.5mH,Rg=25Ω
3. Identical low side and high side switch with identical R_G

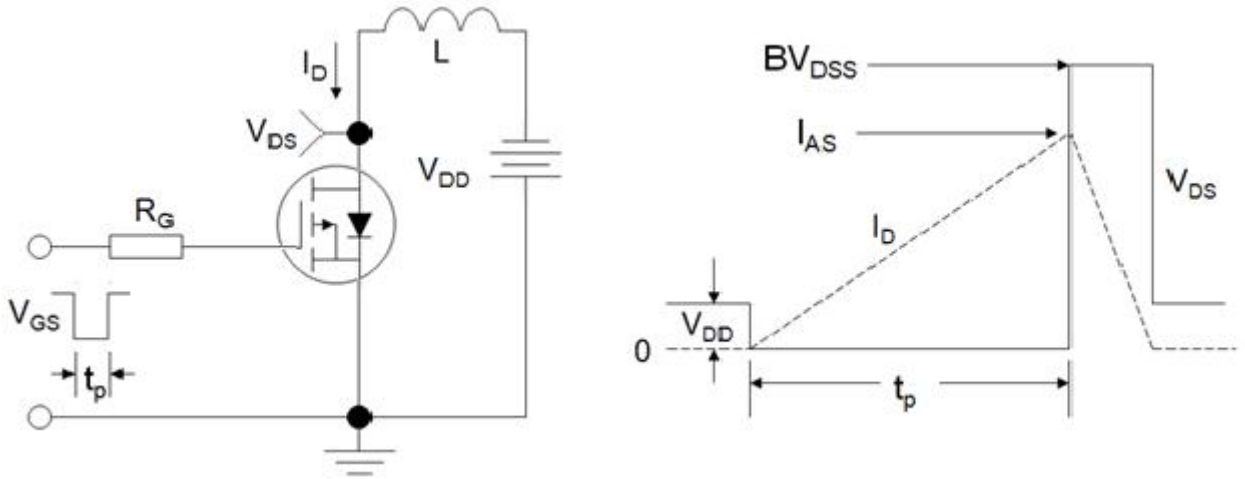
Gate Charge Test Circuit



Switch Time Test Circuit



EAS Test Circuit



Typical Characteristics T_J = 25ºC, unless otherwise noted

Figure 1. Output Characteristics

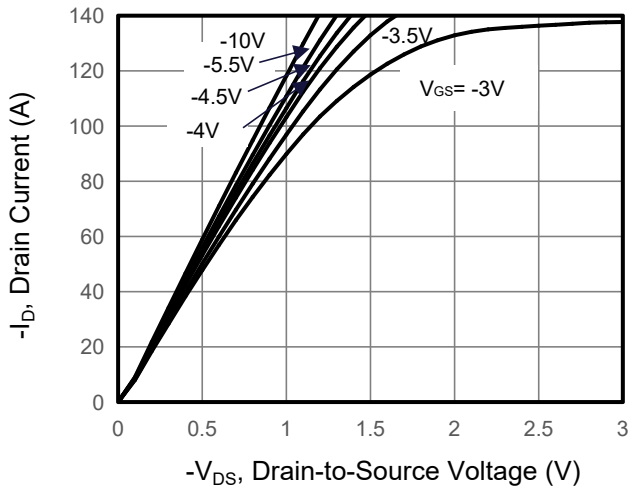


Figure 2. Transfer Characteristics

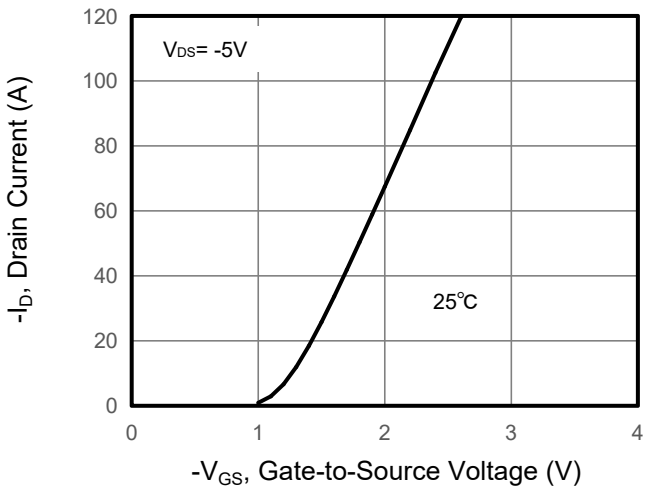


Figure 3.Drain Source On Resistance

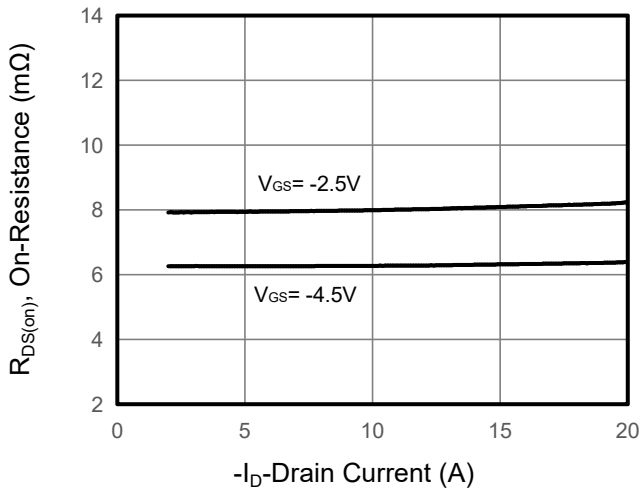


Figure 4. Gate Charge

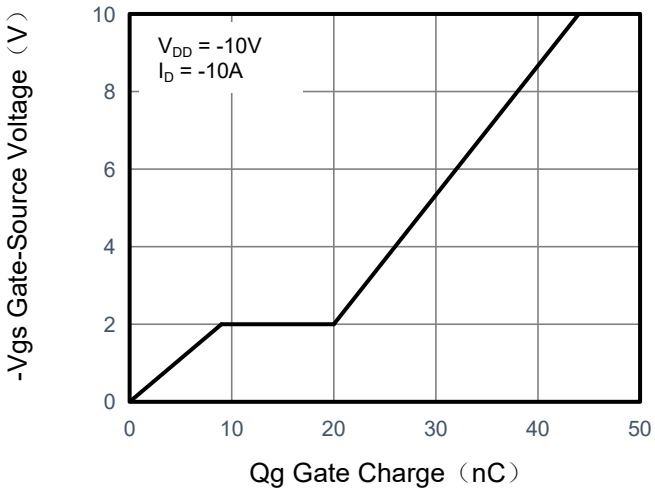


Figure 5. Capacitance

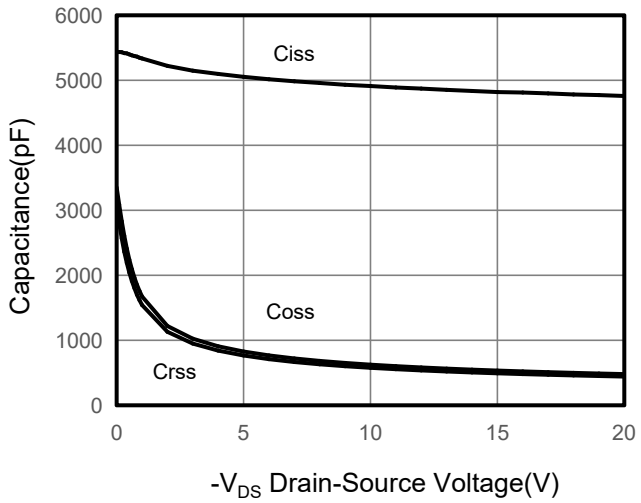
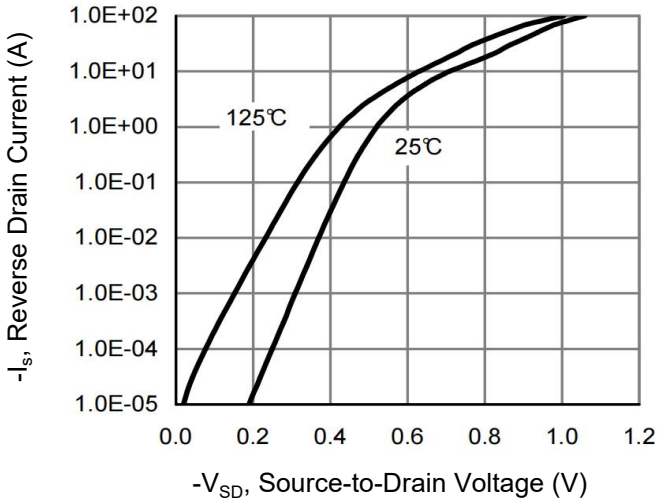


Figure 6. Source-Drain Diode Forward



Typical Characteristics T_J = 25ºC, unless otherwise noted

Figure 7. Drain-Source On-Resistance

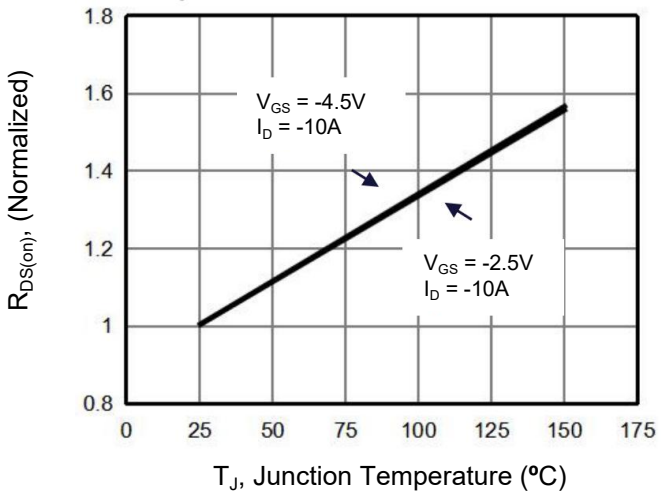


Figure 10. Safe Operation Area

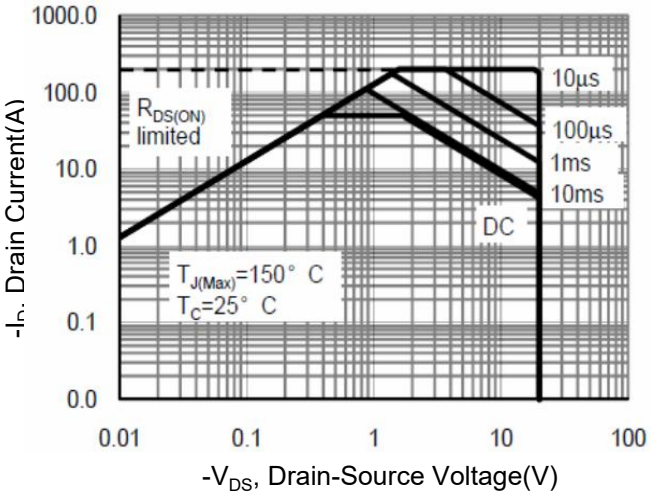
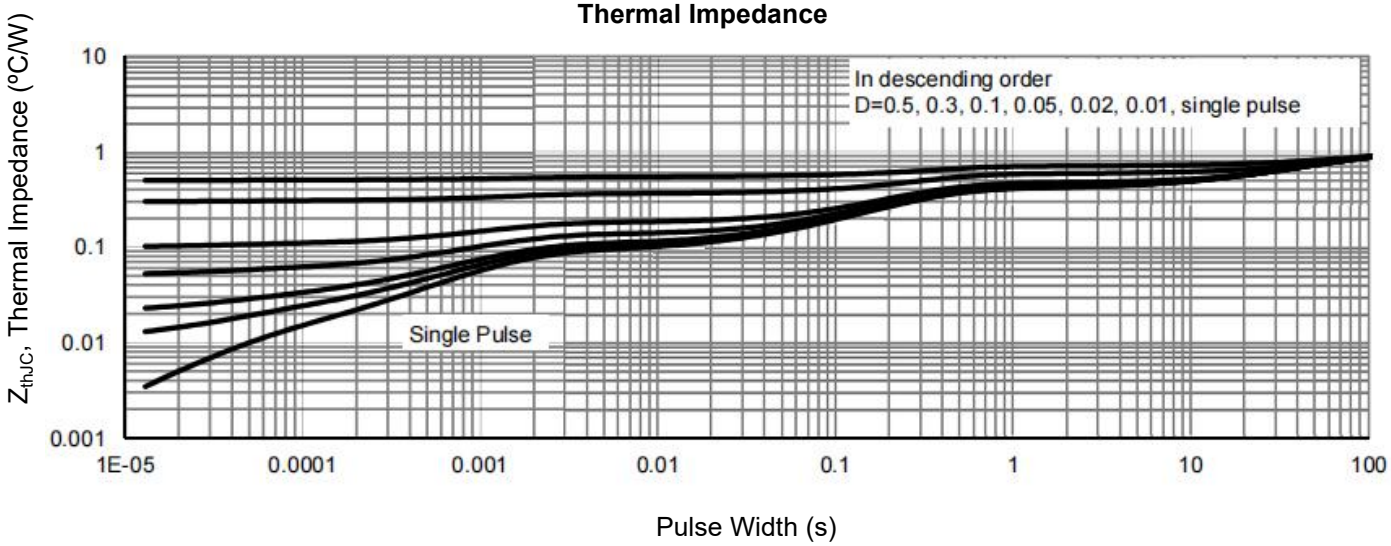
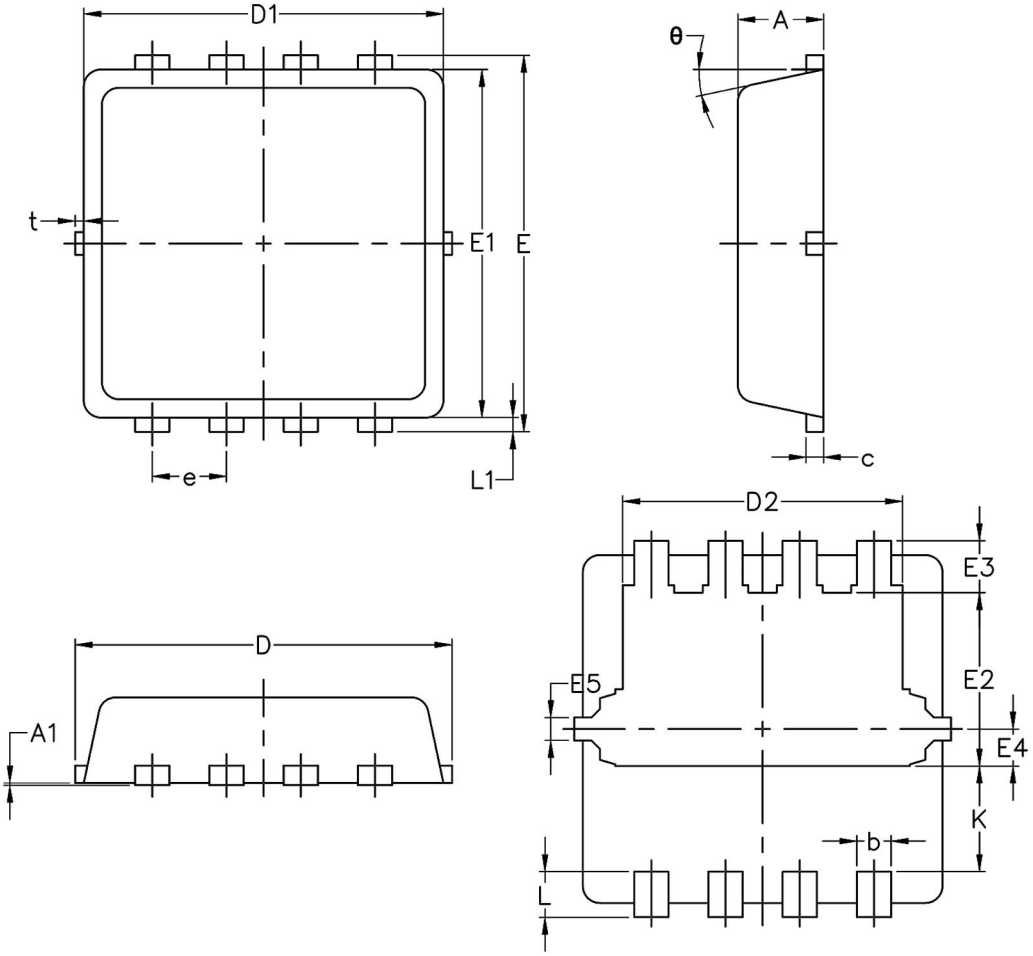


Figure 9. Normalized Maximum Transient Thermal Impedance



DFN3x3-8L Package Information



SYMBOL	COMMON MM			SYMBOL	COMMON MM		
	MIN	NOM	MAX		MIN	NOM	MAX
A	0.70	0.75	0.85	E3	0.28	0.46	0.65
A1	/	/	0.05	E4	0.18	0.33	0.48
b	0.20	0.30	0.40	E5	0.10	0.20	0.30
c	0.10	0.152	0.25	e	0.60	0.65	0.70
D	3.15	3.30	3.45	K	0.78	0.93	1.13
D1	3.00	3.15	3.25	L	0.30	0.40	0.50
D2	2.29	2.45	2.65	L1	0.06	0.125	0.20
E	3.15	3.30	3.45	t	0	0.075	0.13
E1	2.90	3.05	3.20	θ	10°	12°	14°
E2	1.32	1.52	1.72				

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